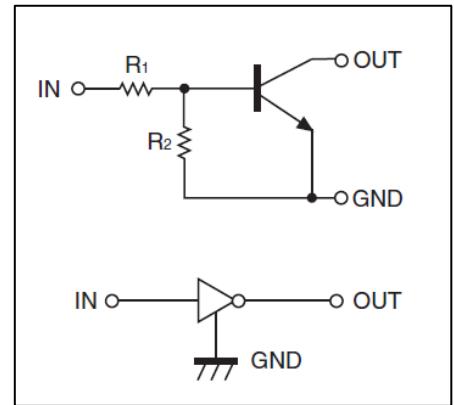


Digital Transistors (Built-in Resistors)

DIGITAL TRANSISTOR (NPN)

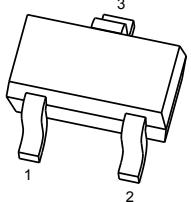
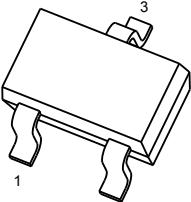
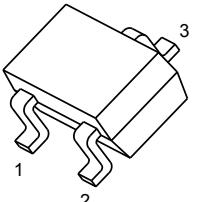
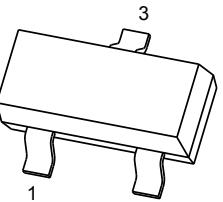
• Equivalent Circuit



FEATURES

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy

PIN CONNECTIONS and MARKING

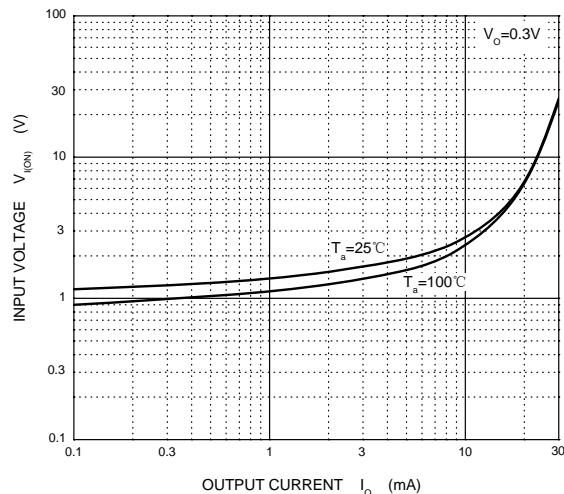
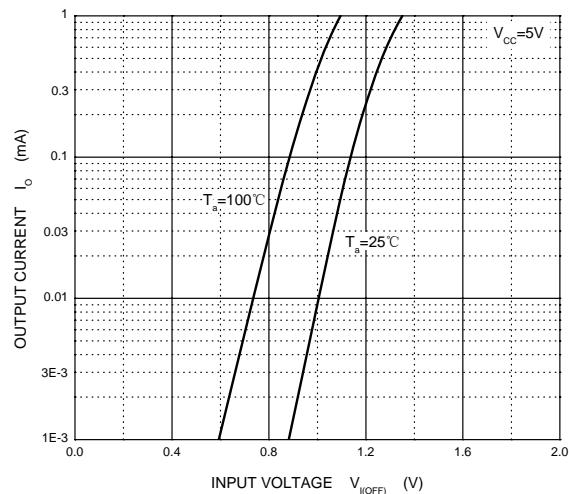
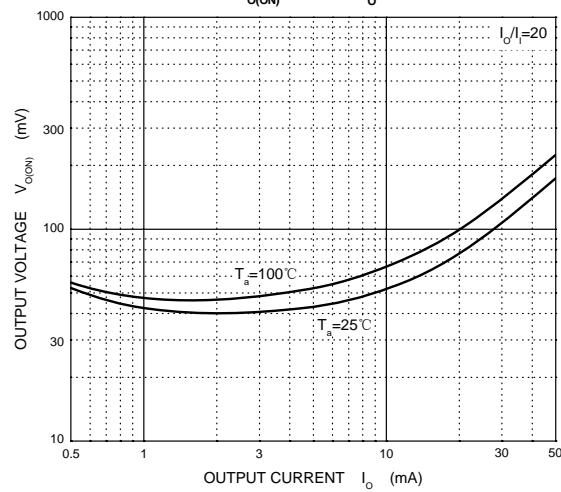
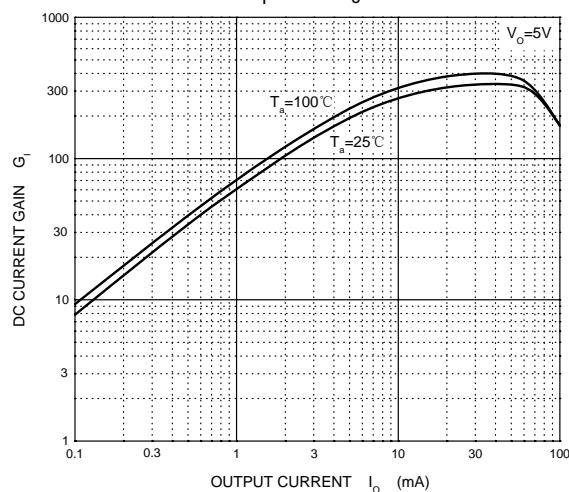
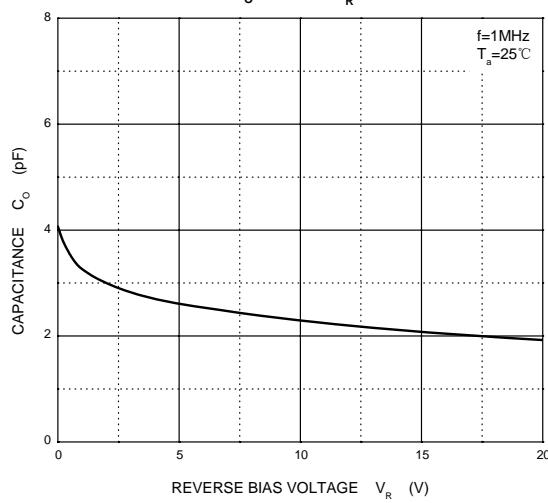
| | | | |
|---|---------------------------|---|---------------------------|
| DTC144EE | SOT-523 | DTC144EUA | SOT-323 |
|  | 1. IN 2. GND 3. OUT |  | 1. IN 2. GND 3. OUT |
| MARKING: 26 | | MARKING: 26 | |
| DTC144EKA | SOT-23-3L | DTC144ECA | SOT-23 |
|  | 1. IN 2. GND 3. OUT |  | 1. IN 2. GND 3. OUT |
| MARKING: 26 | | MARKING: 26 | |

MAXIMUM RATINGS(Ta=25°C unless otherwise noted)

| Symbol | Parameter | Limits(DTC144E□) | | | | Unit |
|------------------|------------------------|------------------|-----|-----|-----|------|
| | | E | UA | CA | KA | |
| V _{CC} | Supply Voltage | 50 | | | | V |
| V _{IN} | Input Voltage | -10~+40 | | | | V |
| I _O | Output Current | 30 | | | | mA |
| I _{CM} | Peak Collector Current | 100 | | | | mA |
| P _D | Power Dissipation | 150 | 200 | 200 | 200 | mW |
| T _j | Junction Temperature | 150 | | | | °C |
| T _{stg} | Storage Temperature | -55~+150 | | | | °C |

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-----------------------------|--------------------------------|--|------|-----|------|------|
| Input voltage | V _{I(off)} | V _{CC} =5V,I _O =100μA | 0.5 | | | V |
| | V _{I(on)} | V _O =0.3V,I _O =2mA | | | 3 | V |
| Output voltage | V _{O(on)} | I _O /I _I =10mA/0.5mA | | | 0.3 | V |
| Input current | I _I | V _I =5V | | | 0.18 | mA |
| Output current | I _{O(off)} | V _{CC} =50V,V _I =0 | | | 0.5 | μA |
| DC current gain | G _I | V _O =5V,I _O =5mA | 68 | | | |
| Input resistance | R _I | | 32.9 | 47 | 61.1 | kΩ |
| Resistance ratio | R ₂ /R _I | | 0.8 | 1 | 1.2 | |
| Transition frequency | f _T | V _O =10V,I _O =5mA,f=100MHz | | 250 | | MHz |

ON Characteristics

OFF Characteristics

 $V_{O(ON)} — I_o$

 $G_i — I_o$

 $C_o — V_R$

 $P_D — T_a$
